Technical Information Fast Switching Thyristor

MS TF1275





Key Parameters

VDRM / VRRM = 2100V= 1275AI_{T(AV)} = 18.5 kA**I**TSM $V_{T(TO)}$ = 1.202V $= 0.340 \text{m}\Omega$ rт

Features

- Full blocking capability over wide temperature
- High Surge current capability
- Hermetic metal case with ceramic insulator
- Distributed gate

- ApplicationsBattery Chargers
- Medical Equipment
- **UPS**
- Power Supplies
- Motor control
- Transportation
- Induction Heating
- Welding

Ordering Information

MS TF	1275	С	XX	F	2J
Fast Switching Thyristor	Current Code	C - Capsule package with Alloyed silicon technology	Voltage Code Code X 100 = V _{DRM} /V _{RRM}	Reapplied dv/dt F = 200V/µsec	Turn Off time code 2J = 50µsec 2N = 60µsec
Order Code MS TF1275C21F2J - 2100V V _{DRM} , V _{RRM} , T _q =50µsec, 26mm clamp height capsule					

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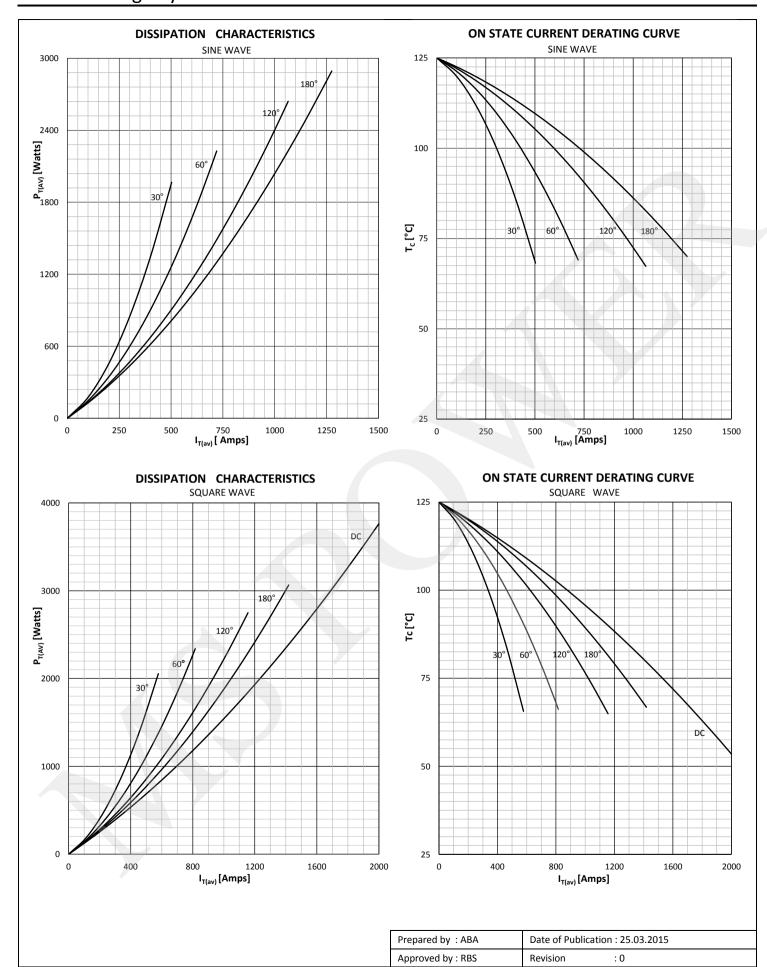
Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
BLOCKI	NG		•		
V RRM	Repetitive peak reverse voltage		125	1200 - 2100	V
V RSM	Non-repetitive peak reverse voltage		125	1200 - 2100	V
V DRM	Repetitive peak off-state voltage		125	1200 - 2100	V
I RRM	Repetitive peak reverse current	V= V RRM	125	150	mA
I DRM	Repetitive peak off-state current	V= V DRM	125	150	mA
CONDU	CTING				
I T (AV)	Mean on state current	180° sin ,50 Hz, T _c =70°C, Double side cooled		1275	Α
I RMS	RMS on-state current			2001	А
		Sine wave, 10 ms	25	18500	Α
I TSM	Surge on-state current	Without reverse voltage	125	17500	Α
10		Sine wave, 10 ms	25	1711 x 10 ³	A ² s
l² t	l² t	Without reverse voltage	125	1531 x 10 ³	A ² s
Vт	On-state voltage	On-state current = 2000A	125	2.00	V
V T(TO)	Threshold voltage		125	1.202	V
rт	On-state slope resistance		125	0.340	mΩ
SWITCH	ING				
di/dt	Critical rate of rise of on-state current	Repetitive	125	250	A/µs
dv/dt	Critical rate of rise of off-state voltage	$V_{DR} = 67\%V_{DRM}$	125	400	V/µs
Tq	Circuit commutated turn off time	I_{TM} =1000A, -dir/dt = 60A/µs, V_R = 100V, t_p =1000µs Reapplied dv/dt = 200V/µs, V_{DR} = 80% V_{DRM}	125	50 - 60	μs
GATE		Reapplied dwdt = 200 V/μs, VDR = 00 70 VDRM			
l _{gt}	Gate trigger current	V _D =6V	25	200	mA
V gt	Gate trigger voltage	V _D =6V	25	3.0	V
I _H	Holding current	V _D =6V, gate open circuit	25	600	mA
I L	Latching current	V _D =6V	25	1000	mA
MOUNT	NG		"		
R th(j-c)	Thermal impedance, sin 180°	Junction to case, Double side cooled		0.019	°C/W
R th(j-c)	Thermal impedance, rec120°	Junction to case, Double side cooled		0.022	°C/W
R th(c-h)	Thermal impedance	Case to heatsink, Double side cooled		0.005	°C/W
Тj	Max. junction temperature			125	°C
	Storage temperature			-40 125	°C
T stg			1	1	
T stg	Clamping Force			22 - 24	kN

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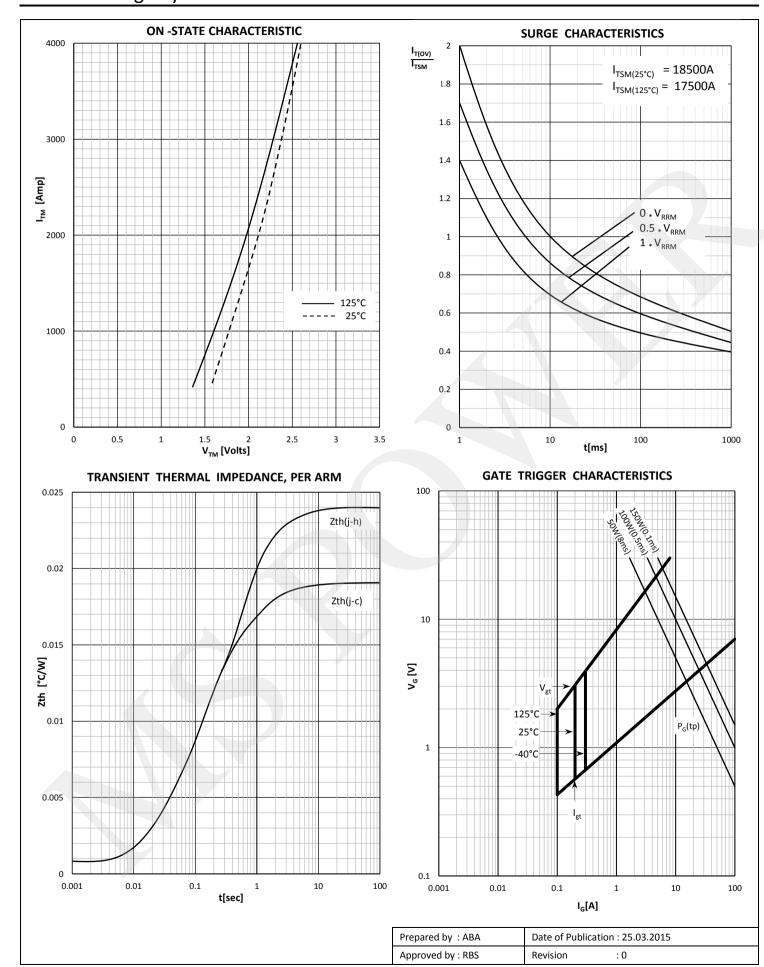




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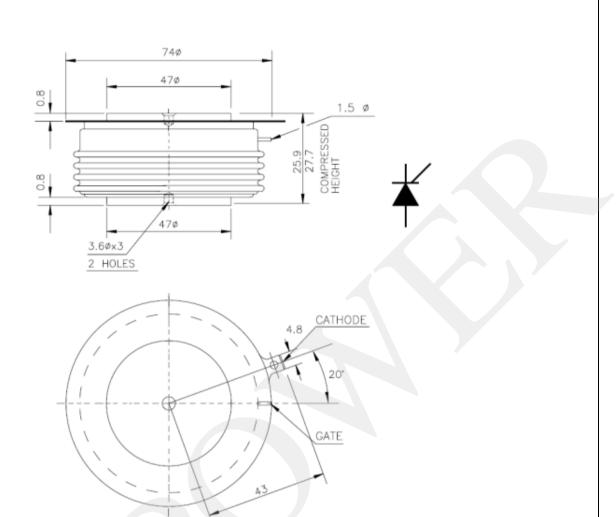




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Outline



MS Power GmbH

Mergenthalerallee 79-81 65760 Eschborn, Germany Web: www.mspowergroup.com Mail: info@mspowergroup.de

Sales & Enquiry:

sales@mspowergroup.de **Technical Support:** solution@mspowergroup.de

After sales Service:

service@mspowergroup.de

Phone: +49 (0) 6196/7768 666 Fax: +49 (0) 6196/7757 888



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